



Four Channel Ultra-Low Capacitance TVS Array



DFN2510-10L

Features

- Reverse Working Voltage : 3.3V
- Ultra-Low Capacitance : 0.28pF (typ.)
- IEC 61000-4-2 (ESD) : ±15kV (air)
- IEC 61000-4-2 (ESD) : ±14kV (contact)
- IEC 61000-4-4 (EFT) : 40A (5/50ns)
- IEC 61000-4-5 (Surge) : 6A (8/20µs)

Application

- V-By-One Interface
- SATA / eSATA Interface
- USB 3.0 / 3.1
- Thunderbolt Interface
- Display Ports Interface

Pinning Information						
Pin	Symbol	Description	Simplified outline	Graphic symbol		
1	I/O 1	Channel 1 ESD protection				
2	I/O 2	Channel 2 ESD protection	N/C N/C GND N/C N/C			
3	GND	Ground				
4	I/O 3	Channel 3 ESD protection				
5	I/O 4	Channel 4 ESD protection				
6	N.C	Not connected				
7	N.C	Not connected				
8	GND	Ground	I/O4 I/O3 GND I/O2 I/O1	<u>=</u> 3,8		
9	N.C	Not connected				
10	N.C	Not connected				

Ordering Information					
Part No.	Remark	Package	Packing		
EZ0P33P2NA-H	Halogen Free	DFN2510-10L	3000 / Tape & Reel		

Maximum Ratings (TA=25°C unless otherwise noted)

Parameter	Symbol	Test conditions	Limit	Unit	
ESD Bating par IEC 61000 4 2	V _{ESD}	Contact	±14		
ESD Rating per IEC 81000-4-2		Air	±15	κv	
Peak Pulse Current	I PP	tp = 8/20 μs	6	А	
Operating Temperature Range	TJ		-55~+ 105	°C	
Storage Temperature Range	Тѕтс		-55~+ 150	°C	





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Electrical Characteristics (TA=25°C unless otherwise noted)						
Parameter	Symbol	Test conditions	Min.	Тур.	Max.	Unit
Reverse Working Voltage	Vrwm	I/O Pin to GND	-	-	3.3	V
		I _T =1mA,	0.5	-	16	V
Breakdown Voltage	VBR	I/O Pin to GND	6.5			
Forward Voltage	\/-	I _F =15mA,		1	-	V
Forward voltage	VF	I/O Pin to GND	-			
Deverse Leekers Current	1-	Vrwm=3.3V,		-	1	uA
Reverse Leakage Current	IR	I/O Pin to GND	-			
Surge Clamping Voltage		IPP=5A,		11.5	-	V
(tp=8/20us)	VC	I/O Pin to GND	-			
		ITLP=1A,		2.5	-	v
TLP Clamping Voltage	Vc -	I/O Pin to GND	-			
(tp=100ns, tr=1ns)		Itlp=16A,		5.5	-	
		I/O Pin to GND	-			
TLP Dynamic Resistance	Bow	I/O Pin to GND -	0.2		0	
(tp=100ns, tr=1ns)	T UYN			0.2		22
		V _R =1.5V, f=1MHz,		0.28	0.33	
lunction Canacitanco	C	I/O Pin to GND	-			рF
Sunction Capacitance		V _R =1.5V, f=1MHz,		0.05	0.1	
		Between I/O Pin	-			

Rating and Characteristics Curves



FIG. 2-Junction Capacitance (I/O Pin to I/O Pin)







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Rating and Characteristics Curves

FIG. 3-Surge Clamping Voltage



FIG. 4-TLP Clamping Voltage (tperiod=100ns,tr=1ns)



FIG. 5-10Gb/s USB3.1 Gen2 Eye Diagram with EZ0P33P2NA



FIG. 6-Insertion Loss







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DFN2510-10L

Dimensions in inches and (millimeters)

Suggested Pad Layout

Outline Dimension	DFN2510-10L (mm)
С	1.025
G	0.35
Р	0.55
P1	1.00
Х	0.30
X1	0.45
Y	0.675
Z	1.70



Tape & Reel Specification

ltom	Symbol	DFN2510-10L		
Item	Symbol	(mm)		
Carrier width	Α	1.20 ± 0.1		
Carrier length	В	2.7 ± 0.1		
Carrier depth	С	0.7 ± 0.1		
Sprocket hole	d	1.35 ± 0.25		
Reel outside diameter	D	178 ± 2.0		
Feed hole diameter	D0	13.25 ± 0.55		
Reel inner diameter	D1	50 (min)		
Sprocket hole position	E	1.75 ± 0.1		
Punch hole position	F	3.5 ± 0.05		
Sprocket hole pitch	Р	4.0 ± 0.1		
Sprocket hole pitch	P0	4.0 ± 0.1		
Embossment center	P1	2.0 ± 0.1		
Overall tape thickness	Т	0.22 ± 0.06		
Tape width	W	8.0 ± 0.3		
Reel width	W2	15.4 (max)		







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